

## CYD175 Hall Effect Latch IC Switch for High Temperature

CYD175 is a single-digital-output Hall-effect sensor for high temperature operation. The device includes an on-chip Hall voltage generator for magnetic sensing, an amplifier to amplify Hall voltage, and a comparator to provide switching hysteresis for noise rejection, and an open-collector output pre-driver. An internal band gap regulator is used to provide temperature compensated supply voltage for internal circuits and allows a wide operating supply range.

While the magnetic flux density ( $B$ ) is larger than threshold  $B_{OP}$ , the OUT pin turns on (low). If  $B$  removed toward  $B_{RP}$ , the OUT pin is latched "on" state prior to  $B < B_{RP}$ . When  $B < B_{RP}$ , the OUT pin go into "off" state.

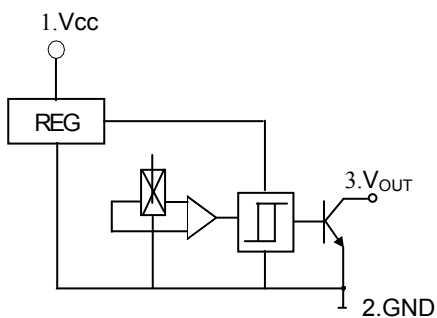
### FEATURES

- Bipolar Hall effect latch sensor
- 3.5V to 20V DC operation voltage
- Open collector pre-driver
- 25mA output sink current
- Chip power reverse-connection protection
- Operating temperature:  $-40^{\circ}\text{C} \sim 150^{\circ}\text{C}$

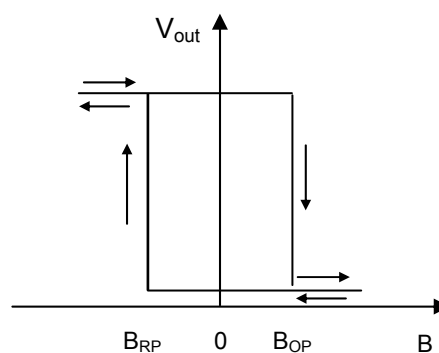
### TYPICAL APPLICATION

- Rotor position sensing
- Current switch
- Encoder
- RPM detection

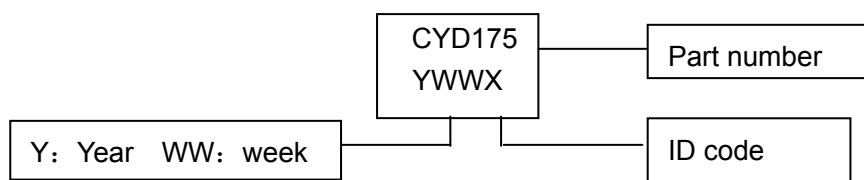
### Block Diagram

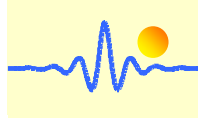


### Magnetic-electrical Transfer Characteristics



### Marking Information





**Absolute Maximum Ratings (At Ta= 25°C)**

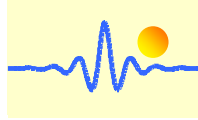
Parameter	Symbol	Value		Unit
		Min	Max	
Supply Voltage	V <sub>CC</sub>	3.5	20	V
Output "OFF" Voltage	V <sub>out (off)</sub>	20		V
Output "ON" Current	I <sub>o (sink)</sub>		25	mA
Operating Temperature Range	T <sub>op</sub>	-40	150	°C
Storage Temperature Range	T <sub>stg</sub>	-65	150	°C
Maximum Junction Temperature	T <sub>j</sub>		150	°C

**Electrical Characteristics (Ta= 25°C )**

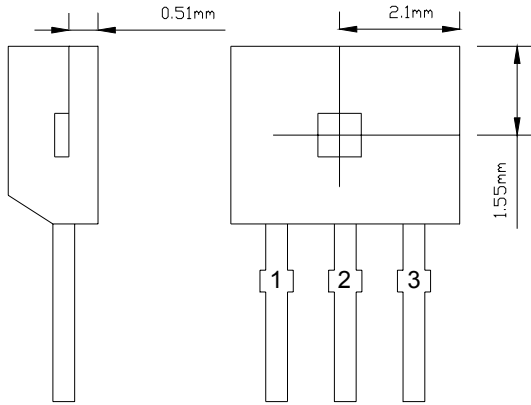
Parameter	Symbol	Conditions	Value			Unit
			Min	Typ	Max	
Supply Voltage	V <sub>CC</sub>		3.5	-	20	V
Output Saturation Voltage	V <sub>out(sat)</sub>	CC=12V, OUT "ON", I <sub>o</sub> =10mA		300	400	mV
Supply Current	I <sub>CC</sub>	VCC=12V, OUT "OFF"		3.5	6.0	mA

**Magnetic Characteristics (Ta= 25°C ) (1mT = 10 Gauss)**

Parameter	Symbol	grade	Value			Unit
			Min	Typ	Max	
Operate Point	B <sub>OP</sub>	A	1.5	4	6	mT
		B	0.5	4	8	
Release Point	B <sub>RP</sub>	A	-6	-4	-1.5	mT
		B	-8	-4	-0.5	
Hysteresis	B <sub>H</sub>	A	3	8	12	mT
		B	10	8	16	



## Package Information



Active Area Depth

Sensor Location

## Pin Descriptions

- 1. VCC Input power
- 2. GND Ground
- 3. OUT Output stage

## Package Dimension

